

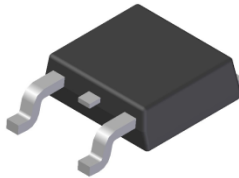
## Features

- $BV_{CEO} > -80V$
- $I_C = -8A$  Continuous Collector Current
- $I_{CM} = -16A$  Peak Pulse Current
- Ideal for Power Switching or Amplification Applications
- Complementary NPN Type: [MJD44H11](#)
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **An automotive-compliant part is available under a separate datasheet ([MJD45H11Q](#))**

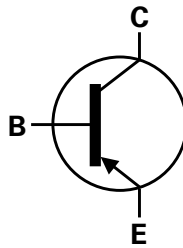
## Mechanical Data

- Package: TO252
- Package Material: Molded Plastic, "Green" Molding Compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 [\(E3\)](#)
- Weight: 0.34 grams (Approximate)

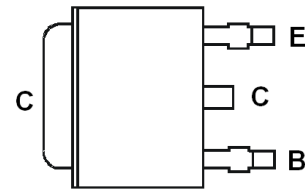
TO252 (DPAK)



Top View



Device Schematic



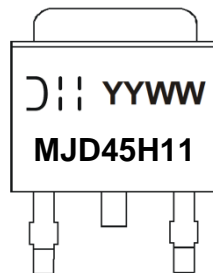
Pin Out Configuration  
Top View

## Ordering Information (Note 4)

Orderable Part Number	Package	Marking	Reel Size (inches)	Tape Width (mm)	Packing	
					Qty.	Carrier
MJD45H11-13	TO252 (DPAK)	MJD45H11	13	16	2,500	Reel

- Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
  2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

## Marking Information



MJD45H11 = Product Type Marking Code  
 D11 = Manufacturer's Code Marking  
 YYWW = Date Code Marking  
 YY = Last Two Digits of Year (ex: 25 = 2025)  
 WW = Week Code (01 to 53)

## Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-100	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-80	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Continuous Collector Current	I <sub>C</sub>	-8	A
Peak Pulse Collector Current	I <sub>CM</sub>	-16	A

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

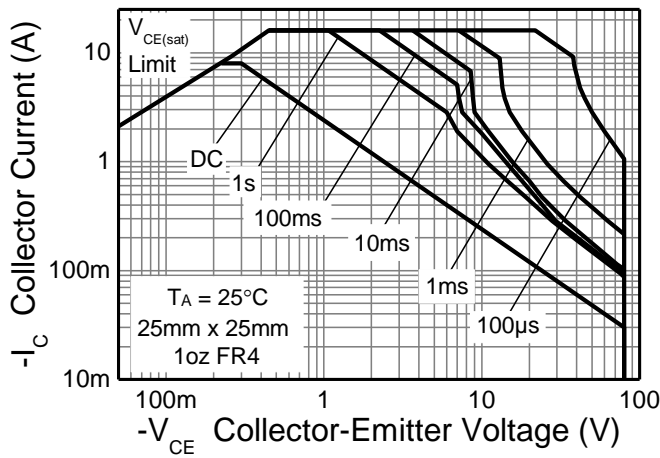
Characteristic	Symbol	Value	Unit
Power Dissipation	P <sub>D</sub>	2.7	W
		2.4	
		1.5	
Thermal Resistance, Junction to Ambient Air	R <sub>θJA</sub>	46	°C/W
		52	
		83	
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

## ESD Ratings (Note 8)

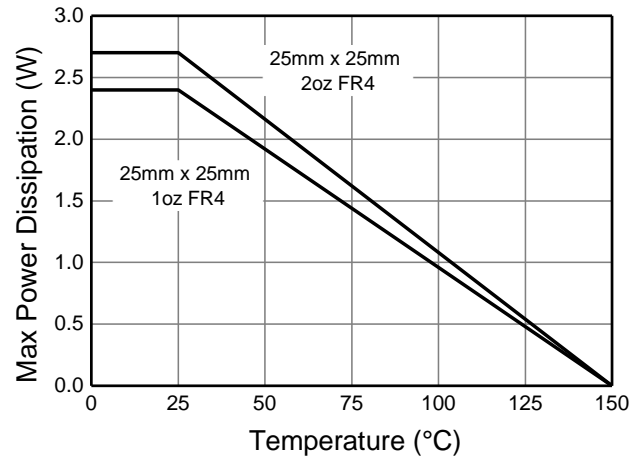
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge — Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge — Charged Device Model	ESD CDM	1,000	V	C3

- Notes:
5. For a device mounted with the exposed collector pad on 25mm x 25mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady state.
  6. Same as Note 5, except mounted on 25mm x 25mm 1oz copper.
  7. Same as Note 5, except mounted on minimum recommended pad (MRP) layout.
  8. Refer to JEDEC specification JS-001-2017 and JS-002-2022.

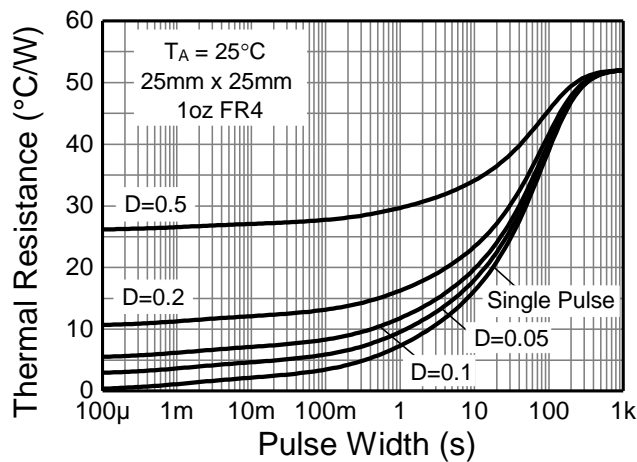
## Thermal Characteristics



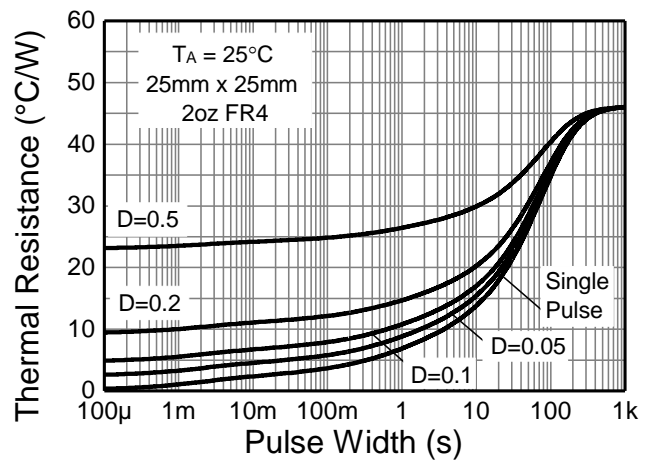
**Figure 1. Safe Operating Area**



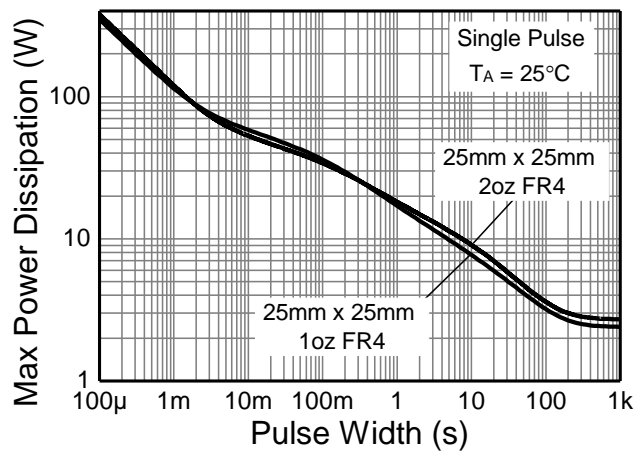
**Figure 2. Derating Curve**



**Figure 3. Transient Thermal Impedance**



**Figure 4. Transient Thermal Impedance**



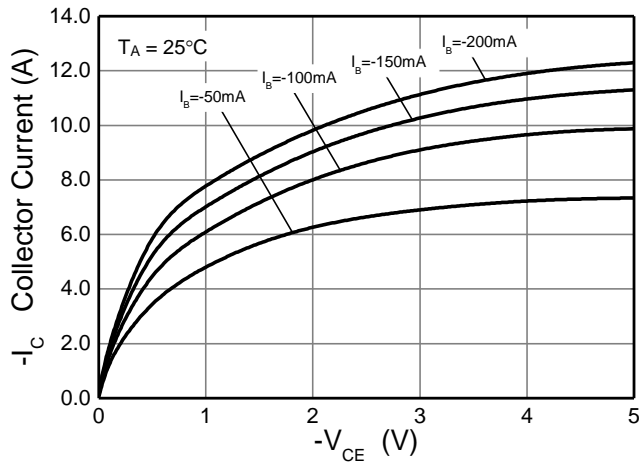
**Figure 5. Pulse Power Dissipation**

# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

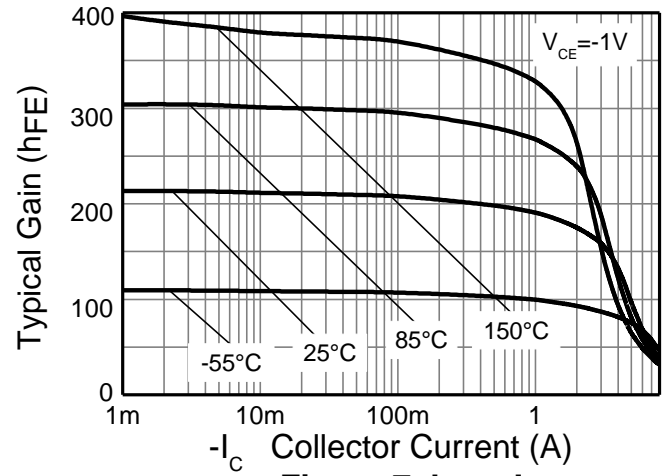
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-100	—	—	V	I <sub>C</sub> = -100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	-80	—	—	V	I <sub>C</sub> = -10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	—	—	V	I <sub>E</sub> = -100μA
Collector Cutoff Current	I <sub>CES</sub>	—	—	-1	μA	V <sub>CE</sub> = -80V
Collector-Base Cutoff Current	I <sub>CBO</sub>	—	—	-100	nA	V <sub>CB</sub> = -80V
Emitter Cutoff Current	I <sub>EBO</sub>	—	—	-1	μA	V <sub>EB</sub> = -6V
Collector-Emitter Saturation Voltage (Note 9)	V <sub>CE(sat)</sub>	—	—	-1	V	I <sub>C</sub> = -8A, I <sub>B</sub> = -400mA
Base-Emitter Saturation Voltage (Note 9)	V <sub>BE(sat)</sub>	—	—	-1.5	V	I <sub>C</sub> = -8A, I <sub>B</sub> = -800mA
Base-Emitter Turn-On Voltage (Note 9)	V <sub>BE(on)</sub>	—	—	-2	V	I <sub>C</sub> = -6A, V <sub>CE</sub> = -4V
DC Current Gain (Note 9)	h <sub>FE</sub>	60 40	— —	— —	—	V <sub>CE</sub> = -1V, I <sub>C</sub> = -2A V <sub>CE</sub> = -1V, I <sub>C</sub> = -4A
Current Gain-Bandwidth Product	f <sub>T</sub>	3	—	—	MHz	V <sub>CE</sub> = -10V, I <sub>C</sub> = -0.5A, f = 100MHz
Output Capacitance	C <sub>obo</sub>	—	85	—	pF	V <sub>CB</sub> = -10V, f = 1MHz
Input Capacitance	C <sub>ibo</sub>	—	835	—	pF	V <sub>EB</sub> = -0.5V, f = 1MHz
Delay Time	t <sub>d</sub>	—	5	—	ns	I <sub>C</sub> = -5A, V <sub>CC</sub> = -12.5V, -I <sub>B1</sub> = I <sub>B2</sub> = 500mA
Rise Time	t <sub>r</sub>	—	105	—	ns	
Storage Time	t <sub>s</sub>	—	155	—	ns	
Fall Time	t <sub>f</sub>	—	15	—	ns	

Note: 9. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

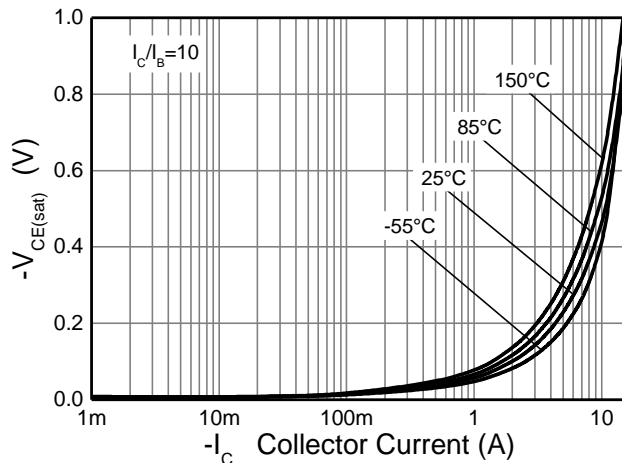
**Typical Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)



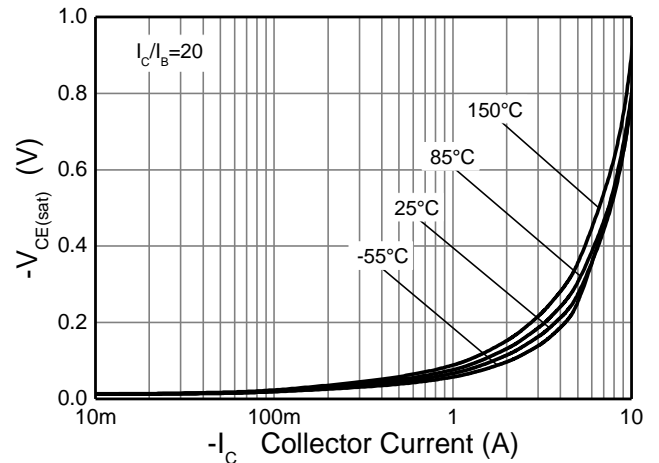
**Figure 6.  $I_C$  v  $V_{CE}$**



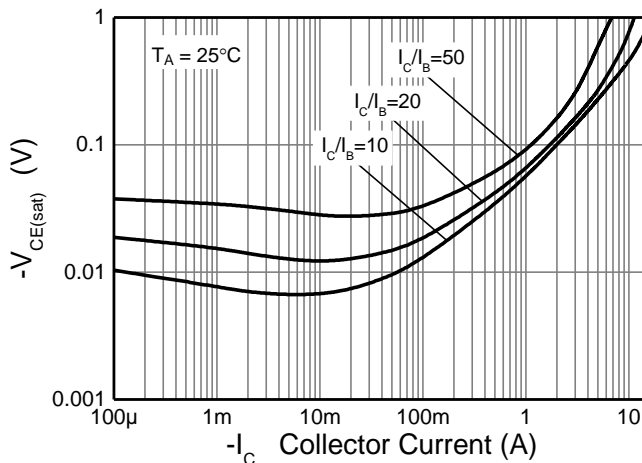
**Figure 7.  $h_{FE}$  v  $I_C$**



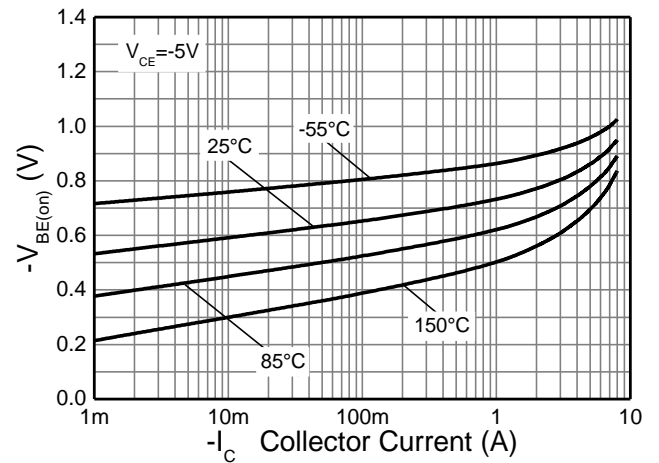
**Figure 8.  $V_{CE(sat)}$  v  $I_C$**



**Figure 9.  $V_{CE(sat)}$  v  $I_C$**

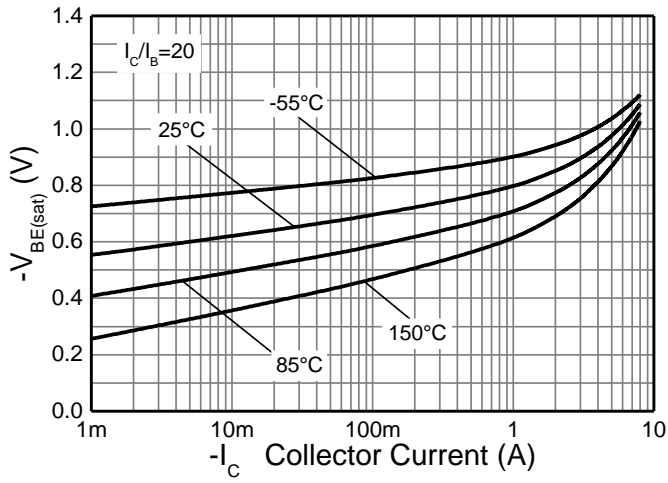


**Figure 10.  $V_{CE(sat)}$  v  $I_C$**



**Figure 11.  $V_{BE(on)}$  v  $I_C$**

**Typical Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.) (continued)

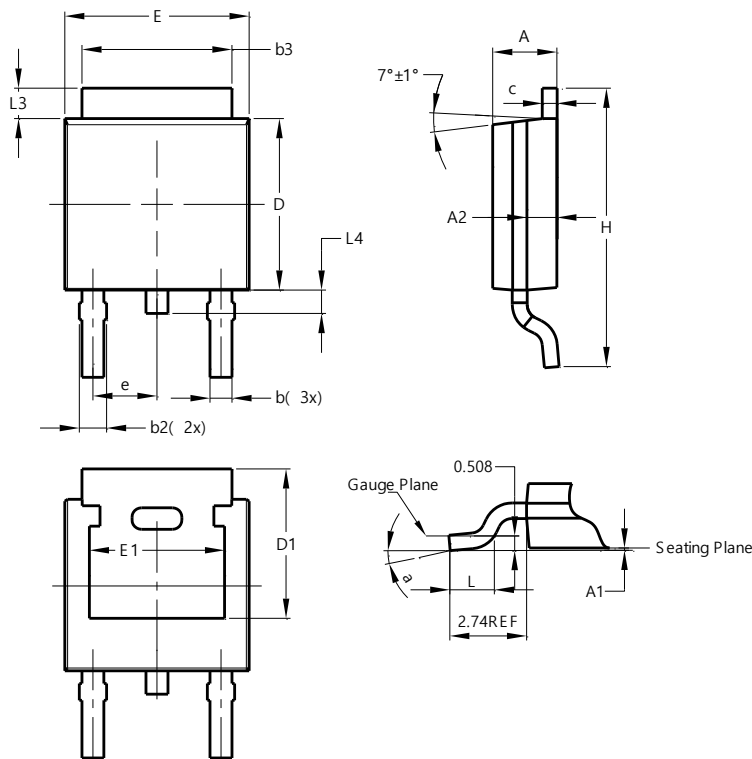


**Figure 12.  $V_{BE(sat)}$  v  $I_C$**

## Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

### TO252 (DPAK)

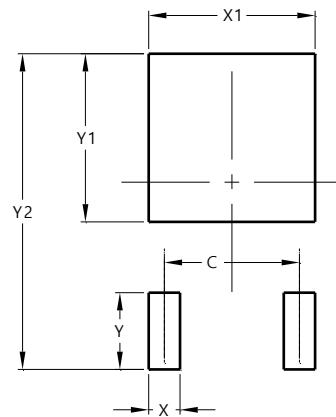


TO252 (DPAK)			
Dim	Min	Max	Typ
A	2.19	2.39	2.29
A1	0.00	0.13	0.08
A2	0.97	1.17	1.07
b	0.64	0.88	0.783
b2	0.76	1.14	0.95
b3	5.21	5.50	5.33
c	0.45	0.58	0.531
D	6.00	6.20	6.10
D1	5.21	--	--
e	2.286 BSC		
E	6.45	6.70	6.58
E1	4.32	--	--
H	9.40	10.41	9.91
L	1.40	1.78	1.59
L3	0.88	1.27	1.08
L4	0.64	1.02	0.83
a	0°	10°	--
All Dimensions in mm			

## Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

### TO252 (DPAK)



Dimensions	Value (in mm)
C	4.572
X	1.060
X1	5.632
Y	2.600
Y1	5.700
Y2	10.700

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